# NSN 5961-01-227-1941

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-227-1941

#### **Inclosure Material:**

Metal

**Overall Length:** 

1.573 inches

# **Overall Height:**

0.450 inches

**Overall Width:** 

1.050 inches

### **Mounting Facility Quantity:**

2

### Internal Configuration:

Field effect

### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

50.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source

# **Current Rating Per Characteristic:**

10.00 milliamperes zero-gate-voltage drain current

#### **Power Rating Per Characteristic:**

500.0 milliwatts total device dissipation

#### **Terminal Type And Quantity:**

2 pin and 1 case

Shelf Life:

N/a

#### Unit Of Measure:

--

# Demilitarization:

Yes - demil/mli

Fiig:

A110a0